

# Differential Hall Effect Transmission Speed Sensors







### **Features**

- · High magnetic sensitivity
- · Large operating airgap
- Two wire PWM current interface
- Fast start-up
- · Dynamic self calibration principle
- Adaptive hysteresis
- Detection of rotation direction
- High vibration suppression capability
- From zero speed up to 12 kHz<sup>1)</sup>
- · Wide operating temperature ranges
- · High resistance to piezo effects
- Single chip solution
- Magnetic encoder and ferromagnetic wheel application
- South and north pole pre-induction possible
- Green package with lead-free plating
- Module style package with integrated overmolded capacitor <sup>2)</sup>
  - 1.8 nF between  $V_{\rm DD}$  and GND
- AEC-Q100 qualified
- Green Product (RoHS compliant)

# **Applications**

The TLE4955C-E4 is an integrated differential Hall effect sensor for transmission applications with two wire PWM output current interface. Its basic function is to provide information about rotational speed and direction of rotation to the transmission control unit. TLE4955C-E4 includes a sophisticated algorithm which actively suppresses vibration while keeping excellent air gap performance.

# **Description**

| Product Name | Ordering Code | Marking | Package     |
|--------------|---------------|---------|-------------|
| TLE4955C-E4  | SP001387576   | 55BIC3  | PG-SSO-2-53 |

<sup>1)</sup> Magnetic parameters are valid and characterized for f > 1 Hz



<sup>2)</sup> Value of capacitor: 1.8 nF +/-10% (excluded drift because of temperature and over lifetime); ceramic: X8R; maximum voltage: 50 V.



### **Family description**

| <b>Product Name</b> | Ordering Code | Marking | Package      |
|---------------------|---------------|---------|--------------|
| TLE4955-E4          | SP001386734   | 55BIA1  | PG-SSO-2-1   |
| TLE4955C-E4         | SP001387576   | 55BIC3  | PG-SSO-2-53  |
| TLE4955C-E2         | SP001387544   | 55BIC2  | PG-SSO-2-53  |
| TLE4955C            | SP001368954   | 55BIC0  | PG-SSO-2-53  |
| TLE4955             | SP001368950   | 55BIA0  | PG-SSO-2-1   |
| TLE4955CB           | SP001368958   | 55BKC0  | PG-SSOM-2-11 |
| TLE4955CB-E2        | SP001387548   | 55BKC1  | PG-SSOM-2-11 |
| TLE4955CB-E4        | SP001467318   | 55BKC2  | PG-SSOM-2-11 |



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### **Functional Description**

#### **Functional Description** 1

The differential Hall sensor IC detects the motion of tooth and magnet encoder applications. To detect the motion of ferromagnetic objects, the magnetic field must be provided by a back biasing permanent magnet. Either south or north pole of the magnet can be attached to the rear unmarked side of the IC package.

The magnetic measurement is based on three equally spaced Hall elements, integrated on the IC.

Both magnetic and mechanical offsets are cancelled by a self calibration algorithm.

The sensor includes a current output PWM protocol.

#### 1.1 **Sensor Assembly**

The output signals for a south biased sensor with a magnetic encoder and ferromagnetic tooth wheel will be issued in the following way.

The tooth wheel is rotating in clockwise above the sensor. The output pulse will be issued by reaching the hysteresis levels after the pre low time. For a tooth wheel with ideal pitch (tooth to tooth) of 5 mm the direction signal achieves a phase shift of 90° compared to the speed signal.

Sensor and back bias magnet can be applied in the following ways:

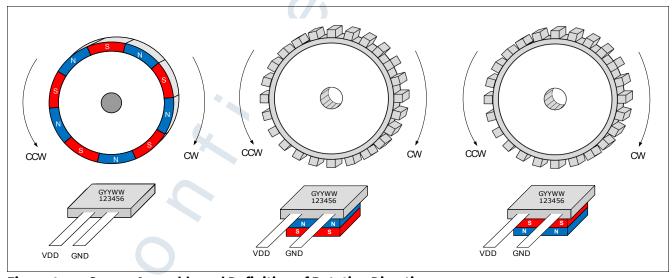
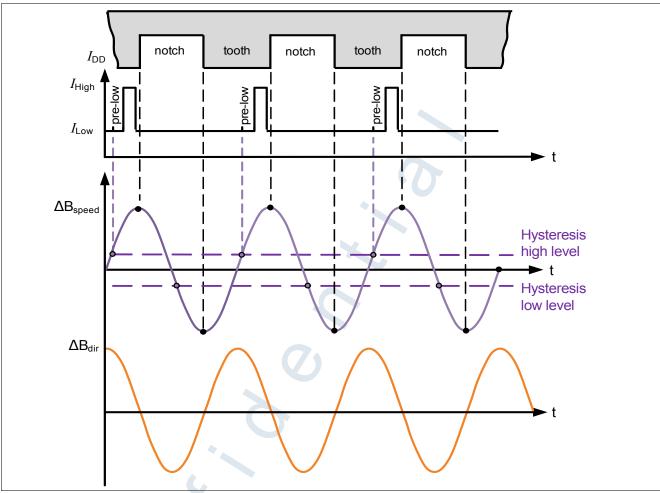


Figure 1 **Sensor Assembly and Definition of Rotating Directions** 



### **Functional Description**



Tooth Wheel vs. Sensor Output Signal in Clockwise Rotation; South Biased Sensor Figure 2



### **Functional Description**

#### 1.2 **Block Diagram**

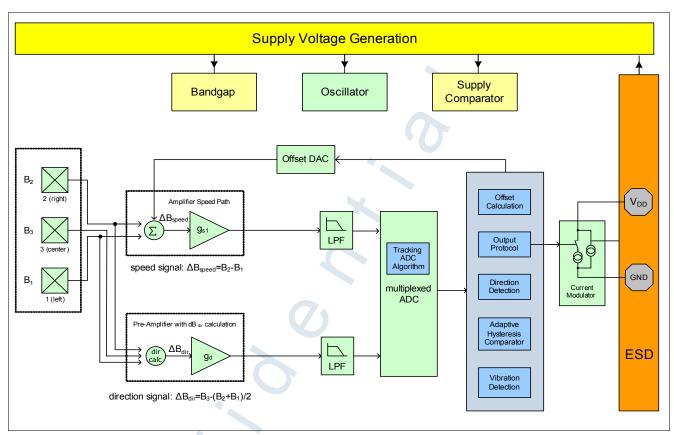


Figure 3 **Block Diagram** 

The speed signal calculated out of B<sub>2</sub>-B<sub>1</sub>, is amplified, low pass filtered and digitized. An algorithm in the digital core for peak detection and offset calculation will be executed. The offset is fed back into the speed signal path with a digital to analog converter for offset correction. The adaptive hysteresis comparator compares the speed signal to the hysteresis value. During uncalibrated mode, the output of the speed pulse is triggered in the digital core by exceeding a certain threshold.

The direction signal is calculated out of the three Hall signals. The direction signal is amplified, filtered, and digitized. In the digital core the direction and the vibration detection information is determined and the data protocol is issued. The direction information is converted to a current modulated signal.



### **Operating Modes and States**

#### 2 **Operating Modes and States**

#### 2.1 **Uncalibrated and Calibrated Mode**

After power on the differential magnetic speed signal is tracked by an analog to digital converter (Tracking ADC) and monitored within the digital core. If the signal slope is identified as a rising edge, the first output pulse is triggered. A second trigger pulse is issued as soon as the next rising edge is detected (see Figure 4). In uncalibrated mode, the output protocols are triggered by the DNC (detection noise constant) in the speed path. After start up the first DNC value is set to  $2x\Delta B_{\text{speed-limit}}$  and after that the DNC is adapted to the magnetic input signal amplitude ( $\Delta B_{\text{speed}}$ ) with a minimum of  $2x\Delta B_{\text{speed-limit}}$ .

The offset update starts if two valid extrema values are found and the direction of the update has the same orientation as the magnetic signal. For example, a positive offset update is being issued on a rising magnetic edge only. The offset update is done independent from the output switching. After a successful offset correction, the sensor is in calibrated mode. Switching occurs at the adaptive hysteresis threshold level.

In calibrated mode, the DNC is adapted to magnetic input signal amplitude (as  $\Delta B_{\text{speed}}/2$ ) with a minimum of  $2x\Delta B_{\text{speed-limit}}$ . The output pulses are then triggered with adaptative hysteresis.

In uncalibrated mode (after start-up or reset) for signals with amplitude smaller than  $2^*\Delta B_{limit}$  (either for direction or speed signal), the sensor always provides the first two pulses and could suppress the third one. The pulse corresponding to the forth magnetic period is calibrated, thus including the direction information.



### **Operating Modes and States**

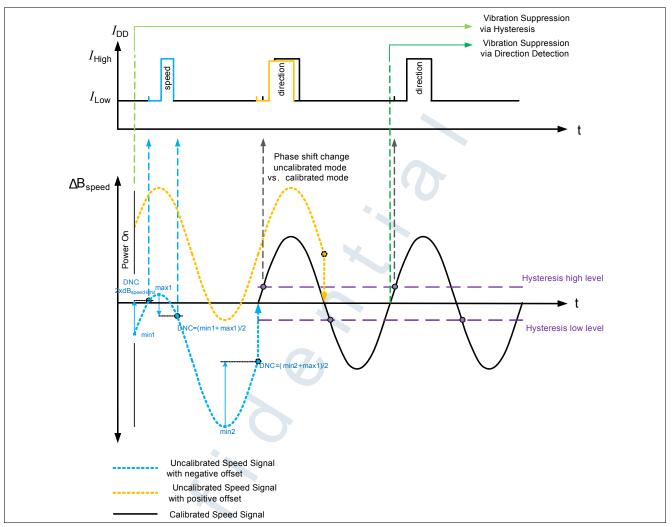


Figure 4 Example for Startup Behavior and Transition from Uncalibrated into Calibrated Mode

### 2.2 Adaptive Hysteresis

The adaptive hysteresis is linked to the input signal. Therefore the system is able to suppress switching if vibration or noise signals are smaller than the adaptive hysteresis levels. The typical value for the hysteresis level is 1/8 of the magnetic input signal amplitude, the minimum hysteresis level is  $\Delta B_{\text{speed-limit}}$  (amplitude). The visible hysteresis keeps the excellent performance in large pitch transmission application wheels .

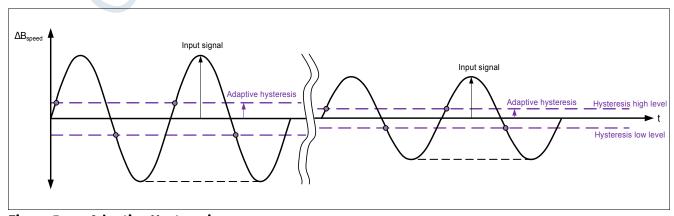


Figure 5 Adaptive Hysteresis



### **Operating Modes and States**

#### 2.3 Direction Detection

The difference between the Hall element signal  $B_3$  and the mean value of the outer Hall elements  $B_2$  and  $B_1$  will be calculated in the direction input amplifier. This signal is digitized by an analog to digital converter (direction ADC) and fed into the digital core.

Depending upon the rotation direction of the target wheel, the signal of the center probe anticipates or lags behind for 90°. This phase relationship is evaluated and converted into rotation direction information by sampling the signal of the center probe in the proximity of the zero crossing of the "speed" bridge signal.

The first pulse after power on is a speed pulse, as there is no valid direction information available.

### 2.4 Vibration Suppression

The magnetic signal amplitude and the direction information are used for detection of parasitic magnetic signals. Unwanted magnetic signal can be caused by angular or air gap vibrations. If an input signal is identified as a vibration the output pulse will be suppressed.

TLE4955C-E4 offers two different kinds of vibration suppression:

- Vibration suppression via hysteresis. This is available after power on
- Vibration suppression via direction detection. This is available after start up calibration is performed.

### 2.5 Undervoltage Behavior

At the first switching events after power on the undervoltage detection is activated.

If the supply voltage drops below the values specified in operating range, an active output (defined state) will be generated. The output level is switched to high current  $(I_{High})$  and it remains at this level until the supply voltage reaches again the functional level.

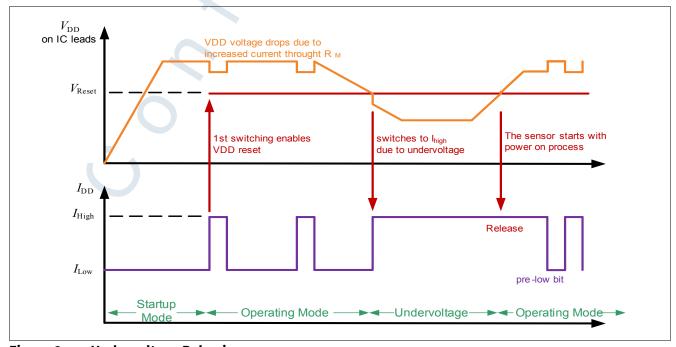


Figure 6 Undervoltage Behavior

If the supply voltage is below 2.3 V typical the sensor will reset and initiate a new calibration.



### **Absolute Maximum Ratings**

# 3 Absolute Maximum Ratings

Attention: Stresses above the max. values listed here may cause permanent damage to the device.

Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolutes ratings; exceeding only one of these values may

cause irreversible damage to the integrated circuit

Table 1 Absolute Maximum Ratings

| Parameter                           | Symbol               |        | Values | 5    | Unit   | <b>Note or Test Condition</b>  |
|-------------------------------------|----------------------|--------|--------|------|--------|--|
|                                     |                      | Min.   | Тур.   | Max. |        |  |
| Supply voltage                      | $V_{DD}$             | -0.3   |        | X    | V      | <i>T</i> <sub>j</sub> < 80 °C  |
|                                     |                      |        |        | 16.5 | V      | T <sub>j</sub> = 170 °C  |
|                                     |                      |        |        | 20   | V      | T <sub>j</sub> = 150 °C  |
|                                     |                      |        |        | 22   | ٧      | t = 10x5  min.   |
|                                     |                      |        |        | 24   | V      | $t = 10x5$ min.; $R_{\rm M} \ge 75$ Ω  |
|                                     |                      |        |        | 27   | ٧      | $t = 400 \text{ms}, R_{\text{M}} \ge 75 \Omega,$                                       |
|                                     |                      | -22    |        |      | V      | $R_{\rm M} = 75 \Omega,  t < 1 {\rm h}$  |
| Junction                            | $T_{\rm J}$ ; Either | -40    |        | 110  | °C     | 12500 h  |
| temperature                         | or                   |        |        | 125  | °C     | 10000 h  |
|                                     | or                   |        |        | 150  | °C     | 5000 h   |
|                                     | or                   |        |        | 160  | °C     | 2500 h   |
|                                     | or                   |        |        | 170  | °C     | 500 h  |
|                                     | additional           |        |        | 190  | °C     | 4 h, V <sub>DD</sub> < 16.5 V  |
| Reverse polarity current            | I DD                 | -200   |        |      | mA     | External current limitation required, $t < 4 \text{ h}$                                |
|                                     | 0                    | -300   |        |      | mA     | External current limitation required, <i>t</i> < 1 h                                   |
|                                     |                      | -200   |        |      | mA     | External current limitation required, $t < 10 \text{ h}$ , $T_j = 25 ^{\circ}\text{C}$ |
| Thermal resistance<br>(PG-SSO-2-53) | $R_{thJA}$           |        |        | 190  | K/W    | Lower values are possible with overmolded devices                                      |
| Number of power on cycles           | n                    | 500000 |        |      | cycles |  |

### 4 ESD Robustness

Characterized according to Human Body Model (HBM) test in compliance with standard EIA/JESD22-A114-B HBM (covers MIL STD 883D)

Table 2 ESD Protection

| Parameter      | Symbol    | Test Result | Unit | Note  |
|----------------|-----------|-------------|------|---|
| ESD-Protection | $V_{ESD}$ | ± 12        | kV   | $R = 1.5 \text{ k}\Omega, C = 100 \text{ pF}$ |



### **Operating Range**

#### **Operating Range** 5

All parameters specified in the following sections refer to these operating conditions unless otherwise noticed.

For further details please refer to relevant Application Note.

Table 3 **Operating Range** 

| Parameter  | Symbol                          | Values    |     |      | Unit | Note or Test Condition  |  |
|--|---------------------------------|-----------|-----|------|------|---|--|
|  |                                 | Min. Typ. |     | Max. |      |   |  |
| Supply voltage   | $V_{\mathrm{DDIC}}$             | 4         |     | 20   | ٧    | Directly on the IC leads  |  |
| Supply voltage modulation  | $V_{AC}$                        |           |     | 6    | V    | $V_{\rm DD}$ = 13 V; 0< $f_{\rm mod}$ < 150 kHz <sup>1)</sup> peak-to-peak  |  |
| Operating junction   | $T_{\rm j}$                     |           |     | X.   |      |   |  |
| temperature  | either                          | -40       |     | 110  | °C   | 12500 h   |  |
|  | or                              |           |     | 125  | °C   | 10000 h   |  |
|  | or                              |           |     | 150  | °C   | 5000 h  |  |
|  | or                              |           | •   | 160  | °C   | 2500 h  |  |
|  | or                              |           |     | 170  | °C   | 500 h   |  |
| Junction temperature variation between two consecutive magnetic edges  | T <sub>j_var</sub>              | -60       |     | 60   | К    | Values apply for $\Delta B_{\rm speed}$ and $\Delta B_{\rm dir} > 2.5\rm mT$ (amplitude) in calibrated mode. In case of uncalibrated sensor, values apply for $\Delta B_{\rm speed}$ and $\Delta B_{\rm dir} > 7.5\rm mT$ (amplitude) <sup>3)</sup> . |  |
| Frequency range of magnetic input signal <sup>2)</sup>   | f                               | 0         |     | 12   | kHz  |   |  |
| Bias-induction <sup>3)</sup>   | Bo                              | -500      |     | +500 | mT   | Magnetic bias induction at the position of each sensing element (B <sub>1</sub> , B <sub>2</sub> , B <sub>3</sub> )   |  |
| Differential biasinduction <sup>3)</sup>   | $\Delta B_{\rm statl/r}$        | -30       |     | +30  | mT   | Difference of the magnetic bia<br>induction between left (B <sub>1</sub> ) an<br>right (B <sub>2</sub> ) sensing element  |  |
| Differential bias-induction<br>between mean value at<br>left, right and center<br>sensing elements <sup>3)</sup> | $\Delta B_{\rm statm/o}$        | -30       |     | +30  | mT   | Difference of the magnetic bia induction between (B <sub>2</sub> +B <sub>1</sub> )/2 and B <sub>3</sub>   |  |
| Speed signal range   | $\Delta B_{\rm speed,range}$    | -120      |     | 120  | mT   |   |  |
| Minimum speed signal   | $\Delta B_{\text{speed-limit}}$ | 0.6       | 1.1 | 2.0  | mT   | Amplitude value<br>99% criteria <sup>4)</sup>   |  |
| Minimum direction signal   | $\Delta B_{ m dir-limit}$       |           | 0.9 | 2.2  | mT   | Amplitude value<br>99% criteria <sup>4)</sup>   |  |

<sup>1)</sup> Sine wave.

<sup>2)</sup> No time based watchdog.

<sup>3)</sup> Not subject to production test, verified by design/characterization.

<sup>4) 99%</sup> criterion stands for 1 out of 100 pulses is missing.



### **Operating Range**

Note: Magnetic parameters are valid for sinusoidal signals and characterized for f > 1 Hz.



#### **Electrical Characteristics**

# **6** Electrical Characteristics

All values specified at constant amplitude and offset of input signal, over operating range, unless otherwise specified. Typical values correspond to  $V_{\rm DD}$  = 12 V and  $T_{\rm i}$  = 25 °C.

**Table 4 Electrical Characteristics** 

| Parameter   | Symbol   |      | Value | S     | Unit       | Note or Test Condition  |  |
|---|--|------|-------|-------|------------|---|--|
|   |  | Min. | Тур.  | Max.  |            |   |  |
| Supply current low  | I <sub>Low</sub>                                 | 6    | 7     | 8     | mA         |   |  |
| Supply current high   | I <sub>High</sub>                                | 12   | 14    | 16    | mA         |   |  |
| Supply current ratio  | I <sub>High</sub> /I <sub>Low</sub>              | 1.9  |       | 2.2   |            |   |  |
| Output rise/fall slew rate  | SR <sub>r</sub> , SR <sub>f</sub>                | 8    | 17    | 26    | mA/μs      | Valid for $t_{\rm r}$ and $t_{\rm f}$ , between 10% and 90% value $R_{\rm M}$ =75 $\Omega$ , $T_{\rm j}$ <175 °C  |  |
| Reset voltage   | V <sub>DD Reset</sub>                            |      | 3.7   | 4     | V          |   |  |
| Power on time <sup>1)</sup>   | t <sub>ON</sub>                                  |      |       | 1     | ms         | V <sub>DD</sub> > 4 V   |  |
| Magnetic edges required for first output pulse <sup>1)</sup>                                    | n <sub>start</sub>                               |      | 7,    | 2     | magn. edge | No vibration, pulse occurs only on rising magnetic edge   |  |
| Number of output pulse until active vibration suppression via hysteresis <sup>1)</sup>          | n <sub>VH-Startup</sub>                          | 6    |       | 0     | pulse      | Active after power on   |  |
| Number of output pulse until active vibration suppression via direction detection <sup>1)</sup> | n <sub>VD-Startup</sub>                          |      |       | 2     | pulse      | vibration suppression<br>activated with complete 3 <sup>rd</sup><br>magnetic signal period  |  |
| Number of magnetic periods generating   | n <sub>DR-Start</sub>                            |      |       | 1     | pulse      | $\Delta B_{\text{dir}} \ge 2^* \Delta B_{\text{dir-limit}}$ and $\Delta B_{\text{speed}} \ge 2^* \Delta B_{\text{speed-limit}}$   |  |
| missing output pulses or pulse without direction information <sup>1)</sup>                      |  |      |       | 1     | pulse      | $\Delta B_{\rm dir} > 1.25^* \Delta B_{\rm dir-limit}$ and $\Delta B_{\rm speed} > 1.25^* \Delta B_{\rm speed-limit}$ and $f \le 2.5$ kHz <sup>2)</sup>   |  |
|   |  |      |       | 3     | pulse      | $ \Delta B_{\text{dir-limit}} < \Delta B_{\text{dir}} < 2^* \Delta B_{\text{dir-limit}} $ or $\Delta B_{\text{speed-limit}} < \Delta B_{\text{speed}} < 2^* \Delta B_{\text{speed-limit}} $ $ 2^* \Delta B_{\text{speed-limit}} $ |  |
| Invalid direction after change of direction <sup>1)</sup>                                       | $n_{IAC}$  |      |       | 1     | pulse      | $2^{\rm nd}$ pulse correct if $\Delta B_{\rm dir}$ $\geq$ $\Delta B_{\rm dir-limit}$  |  |
| Period Jitter <sup>1)</sup> , f ≤ 2500 Hz   | S <sub>Jit-far</sub> ,<br>T <sub>j</sub> ≤150 °C |      |       | ± 1.6 | %          | 1σ value <sup>4)</sup> , $V_{DD}$ =12 V, $\Delta B_{\text{speed}}$<br>>2 mT (amplitude)   |  |
|   | S <sub>Jit-far</sub> ,<br>T <sub>j</sub> ≤170 °C |      |       | ± 2.4 | %          |   |  |



### **Timing Characteristics**

**Table 4 Electrical Characteristics** (cont'd)

| Parameter                                       | Symbol   | Values |      |       | Unit | Note or Test Condition   |
|---|--|--------|------|-------|------|--|
|   |  | Min.   | Тур. | Max.  |      |  |
| Period Jitter <sup>1)</sup> , 2500Hz< f< 12 kHz | S <sub>Jit-far</sub> ,<br>T <sub>j</sub> ≤150 °C |        |      | ± 2.7 | %    | 1σ value <sup>5)</sup> , V <sub>DD</sub> =12 V,<br>ΔB <sub>speed</sub> ≥2 mT (amplitude)                                   |
|   | S <sub>Jit-far</sub> ,<br>T <sub>j</sub> ≤170 °C |        |      | ± 4.0 | %    |  |
| Period Jitter at board net ripple <sup>1)</sup> | S <sub>Jit-AC</sub>                              |        |      | ±2.0  | %    | $V_{\rm CC}$ = 13 V <u>+</u> 3 $V_{\rm pp}$ ;<br>1 $\sigma$ ; 0< $f_{\rm mod}$ <150 kHz;<br>$\Delta B_{\rm speed}$ =7.5 mT |

- 1) Not subject to production test, verified by design/characterization.
- 2) All conditions must be applied simultaneously.
- 3) Either condition or both simultaneously need to be applied.
- 4) Values based on  $3\sigma$  measurements.

# 7 Timing Characteristics

Between each magnetic transition and the rising edge of the corresponding output pulse, the output current is low for  $t_{\rm pre-low}$  in order to allow reliable internal conveyance. After pre low time the output current level is set to high.

After power on the speed pulse is being issued. As soon as the sensor has enough information to recognize the direction of the target wheel, the output pulse will include the direction information.



### **Timing Characteristics**

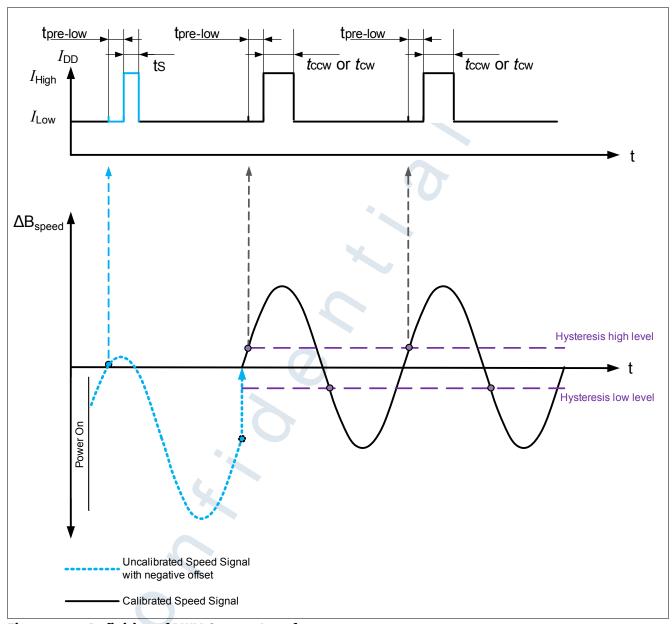


Figure 7 **Definition of PWM Current Interface** 

**Timing Characteristics** Table 5

| Parameter             | Symbol               |       | Values |        |    | Note or Test Condition     |
|-----------------------|----------------------|-------|--------|--------|----|----------------------------|
|                       |                      | Min.  | Тур.   | Max.   |    |                            |
| Pre-low length        | t <sub>pre-low</sub> | 13.12 | 15     | 16.87  | μs |                            |
| lenght of first pulse | t <sub>S</sub>       | 26.25 | 30     | 33.75  | μs | First pulse after power on |
| Length of CCW pulse   | $t_{\sf CCW}$        | 78.75 | 90     | 101.25 | μs |                            |
| Length of CW pulse    | $t_{\sf CW}$         | 39.37 | 45     | 50.62  | μs |                            |
| CW / CCW pulse        | $f_{CW}$             | 12000 |        |        | Hz |                            |
| maximum frequency     | $f_{\sf CCW}$        | 8000  |        |        | Hz |                            |



### **Timing Characteristics**

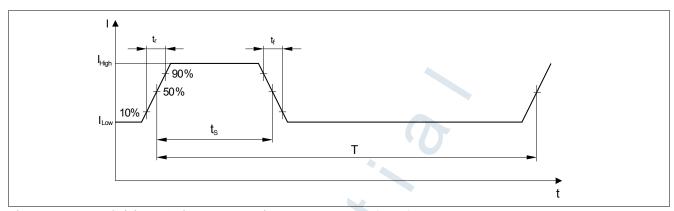


Figure 8 Definition of Rise and Fall time; Duty Cycle=  $(t_s / T) \times 100\%$ 



### **Electromagnetic Compatibility**

#### **Electromagnetic Compatibility** 8

Electromagnetic Compatibility (values depends on  $R_M$ !). See Figure 9

Note:

Characterization of Electro Magnetic Compatibility is carried out on samples based on one qualification lot. Not all specification parameters have been monitored during EMC exposure. Only key parameters e.g. switching current have been monitored.

#### Table 6 **Conducted Pulses**

REF. ISO 7637-2; 2004;  $\Delta B_{\text{speed}} = 2 \text{ mT (amplitude of sinus signal)}; V_{\text{DD}} = 13.5 \text{V}; f_{\text{B}} = 100 \text{ Hz}; T_{\text{j}} = 25 \text{ °C}; R_{\text{M}} = 75 \Omega$ 

| Parameter                  | Symbol    | Level/Type               | Status          |
|----------------------------|-----------|--------------------------|-----------------|
| Testpulse 1                | $V_{EMC}$ | IV / -100 V              | С               |
| Testpulse 2a <sup>1)</sup> |           | IV / 75 V                | A <sup>2)</sup> |
| Testpulse 2b               |           | - / 10 V                 | C <sub>3)</sub> |
| Testpulse 3a               |           | IV / -150 V              | A               |
| Testpulse 3b               |           | IV / 100 V               | A               |
| Testpulse 4 <sup>4)</sup>  |           | IV / -7 V                | С               |
| Testpulse 5a               |           | IV / 86.5 V              | С               |
| Testpulse 5b               |           | Us*=28.5 V <sup>5)</sup> | С               |

- 1) ISO 7637-2 describes internal resistance =  $2 \Omega$  (former 10  $\Omega$ )
- 2) Node A does not exceed 27 V clamping voltage of D2 in any case; Design target!
- 3) Ri=0.01  $\Omega$
- 4) Testpulse4 tested for  $V_{DD}$ =12 V
- 5) A central load dump protection of 42 V is used. Us\*=42 V-13.5 V

#### Table 7 **Coupled Pulses**

REF. ISO 7637-3; 1995;  $\Delta B_{speed}$ =2 mT (amplitude of sinus signal); VDD=13.5 V; fB=100 Hz; Tj=25 °C;  $R_M$ =75 Ω

| Parameter    | Symbol | Level/Typ  | Status |
|--------------|--------|------------|--------|
| Testpulse 3a |        | IV / -60 V | A      |
| Testpulse 3b |        | IV / 40 V  | A      |

#### Table 8 **TEM-cell measurement**

REF. ISO 11452-3, 2nd edition 2001-03-01; measured in TEM-cell;  $\Delta B_{\text{speed}} = 2 \text{ mT}$  (amplitude of sinus signal)  $VDD = 13.5 \text{ V}; f_B = 100 \text{ Hz}; T = 25 °C; R_M = 75 Ω$ 

| Parameter | Symbol               | Level/Typ    | Status          |
|-----------|----------------------|--------------|-----------------|
|           | E <sub>TemCell</sub> | IV / 250 V/m | CW; AM=80%, f=1 |
|           |                      |              | kHz             |



### **Electromagnetic Compatibility**

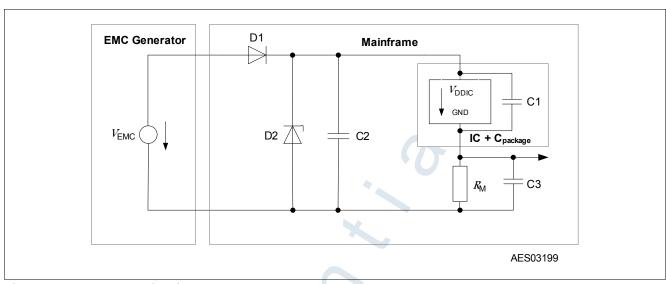


Figure 9 EMC test circuit

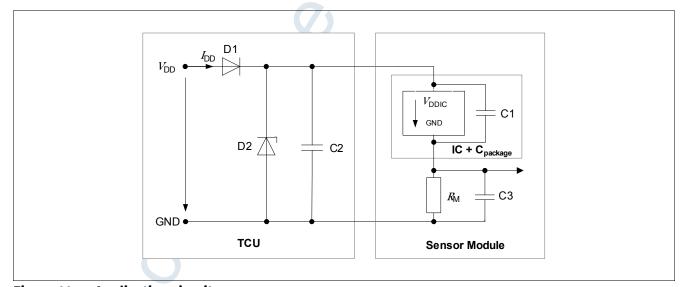


Figure 10 Application circuit

Components

D1= 1N4007

D2= 27 V

C1= 1.8nF / 50 V

 $C2 = 10 \mu F / 35 V$ 

C3= 1 nF / 1000 V

 $R_M = 75 \Omega$ 

18



# 9 Package Information

Pure tin covering (green lead plating) is used. Lead frame material is copper based, e.g. K62. (UNS:C18090) and contains CuSn1CrNiTi. Product is RoHS (Restriction of hazardous Substances) compliant and marked with the letter G in front of the data code marking and may contain a data matrix code on the rear side of the package (see also information note 136/03). Please refer to your key account team or regional sales if you need further information.

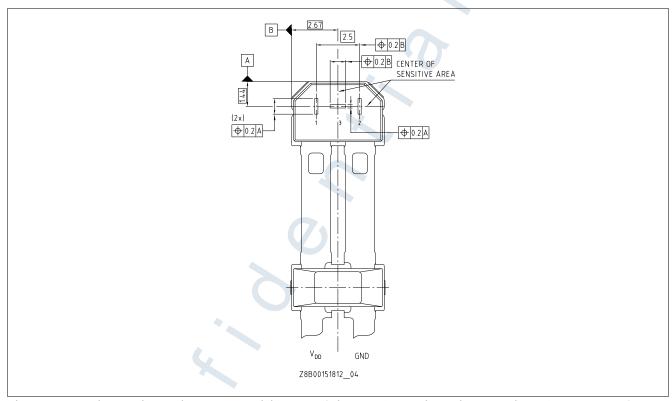


Figure 11 Pin configuration and sensitive area (view on front side with marking of component)

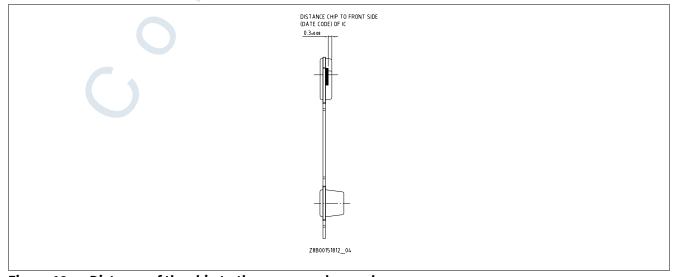


Figure 12 Distance of the chip to the upper package edge



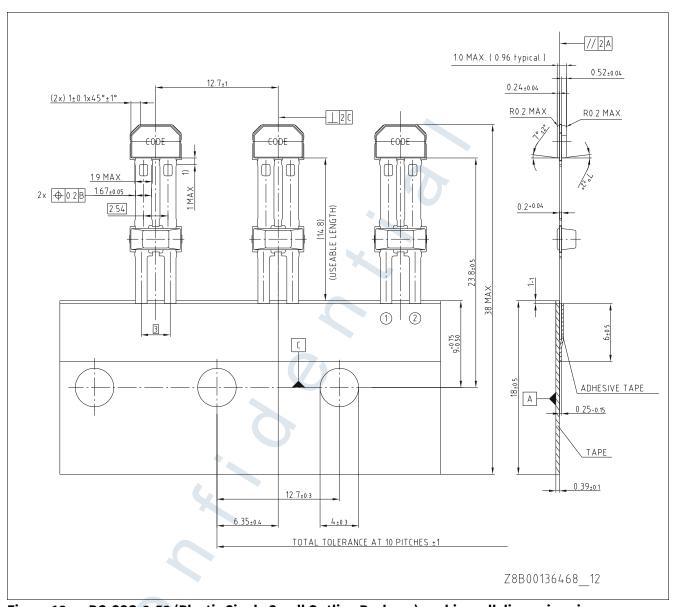


Figure 13 PG-SSO-2-53 (Plastic Single Small Outline Package) packing, all dimensions in mm



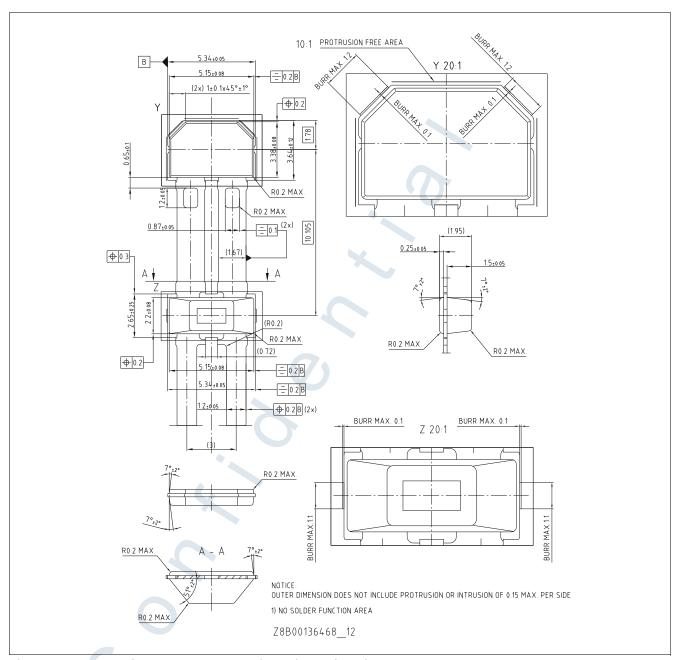


Figure 14 PG-SSO-2-53 package outline, dimensions in mm.



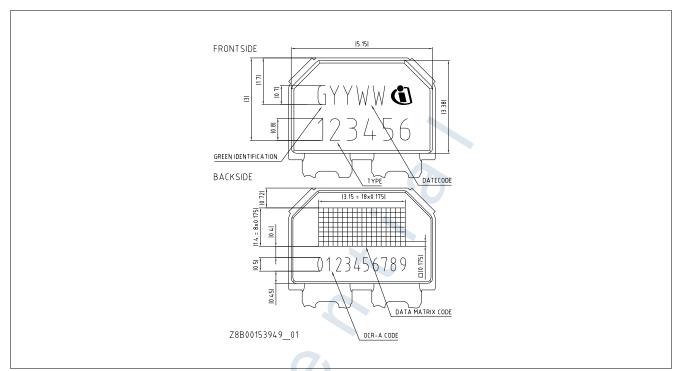


Figure 15 Marking of PG-SSO-2-53

Table 9 Marking Description

| GYYWW | *               | 123456 |  |
|-------|-----------------|--------|--|
| G     | Green package   | 55BIC3 |  |
| YY    | Production year |        |  |
| WW    | Production week |        |  |

For additional packages information, sort of packing and others, please see Infineon internet web page http://www.infineon.com/products



| Revision History |  |  |
|------------------|--|--|
| Page or Item     | Subjects (major changes since previous revision) |  |
|                  | First version of released datasheet              |  |
|                  |  |  |
|                  |  |  |

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